

SOLID STATE (QB) V SEM

1. Which of the following conditions favours the existence of a substance in the solid state?
 - (i) High temperature
 - (ii) Low temperature
 - (iii) High thermal energy
 - (iv) Weak cohesive forces
2. Which of the following is not a characteristic of a crystalline solid?
 - (i) Definite and characteristic heat of fusion.
 - (ii) Isotropic nature.
 - (iii) A regular periodically repeated pattern of arrangement of constituent particles in the entire crystal.
 - (iv) A true solid
3. Which of the following is an amorphous solid?
 - (i) Graphite (C)
 - (ii) Quartz glass (SiO₂)
 - (iii) Chrome alum
 - (iv) Silicon carbide (SiC)
4. Which of the following is true about the value of refractive index of quartz glass?
 - (i) Same in all directions
 - (ii) Different in different directions
 - (iii) Cannot be measured
 - (iv) Always zero
5. Which of the following statement is not true about amorphous solids?
 - (i) On heating they may become crystalline at certain temperature.
 - (ii) They may become crystalline on keeping for long time.
 - (iii) Amorphous solids can be moulded by heating.
 - (iv) They are anisotropic in nature.
6. The sharp melting point of crystalline solids is due to _____.
 - (i) a regular arrangement of constituent particles observed over a short distance in the crystal lattice.
 - (ii) a regular arrangement of constituent particles observed over a long distance in the crystal lattice.
 - (iii) same arrangement of constituent particles in different directions.
 - (iv) different arrangement of constituent particles in different directions
7. Iodine molecules are held in the crystals lattice by _____.
 - (i) london forces
 - (ii) dipole-dipole interactions
 - (iii) covalent bonds
 - (iv) coulombic forces
8. Which of the following is a network solid?
 - (i) SO₂ (Solid)

- (ii) I_2
- (iii) Diamond
- (iv) H_2O (Ice)

9. Which of the following solids is not an electrical conductor?

- (A) Mg (s) (B) TiO (s) (C) I_2 (s) (D) H_2O (s)

- (i) (A) only
- (ii) (B) Only
- (iii) (C) and (D)
- (iv) (B), (C) and (D)

10. Which of the following is not the characteristic of ionic solids?

- (i) Very low value of electrical conductivity in the molten state.
- (ii) Brittle nature.
- (iii) Very strong forces of interactions.
- (iv) Anisotropic nature.

11. Graphite is a good conductor of electricity due to the presence of _____.

- (i) lone pair of electrons
- (ii) free valence electrons
- (iii) cations
- (iv) anions

12. Which of the following oxides behaves as conductor or insulator depending upon temperature?

- (i) TiO
- (ii) SiO_2
- (iii) TiO_3
- (iv) MgO

13. Which of the following oxides shows electrical properties like metals?

- (i) SiO_2
- (ii) MgO
- (iii) SO_2 (s)
- (iv) CrO_2

14. The lattice site in a pure crystal cannot be occupied by _____.

- (i) molecule
- (ii) ion
- (iii) electron
- (iv) atom

15. Graphite cannot be classified as _____.

- (i) conducting solid
- (ii) network solid
- (iii) covalent solid
- (iv) ionic solid

16. Cations are present in the interstitial sites in _____.

- (i) Frenkel defect

- (ii) Schottky defect
- (iii) Vacancy defect
- (iv) Metal deficiency defect

17. Schottky defect is observed in crystals when _____.

- (i) some cations move from their lattice site to interstitial sites.
- (ii) equal number of cations and anions are missing from the lattice.
- (iii) some lattice sites are occupied by electrons.
- (iv) some impurity is present in the lattice.

18. Which of the following is true about the charge acquired by p -type semiconductors?

- (i) positive
- (ii) neutral
- (iii) negative
- (iv) depends on concentration of p impurity

19. To get a n -type semiconductor from silicon, it should be doped with a substance with valence _____.

- (i) 2
- (ii) 1
- (iii) 3
- (iv) 5

20. The total number of tetrahedral voids in the face centred unit cell is _____.

- (i) 6
- (ii) 8
- (iii) 10
- (iv) 12

21. Which of the following point defects are shown by $\text{AgBr}(s)$ crystals?

- (A) Schottky defect (B) Frenkel defect
- (C) Metal excess defect (D) Metal deficiency defect
- (i) (A) and (B)
- (ii) (C) and (D)
- (iii) (A) and (C)
- (iv) (B) and (D)

22. In which pair most efficient packing is present?

- (i) hcp and bcc
- (ii) hcp and ccp
- (iii) bcc and ccp
- (iv) bcc and simple cubic cell

23. The percentage of empty space in a body centred cubic arrangement is _____.

- (i) 74
- (ii) 68
- (iii) 32
- (iv) 26

24. Which of the following statement is not true about the hexagonal close packing?
- (i) The coordination number is 12.
 - (ii) It has 74% packing efficiency.
 - (iii) Tetrahedral voids of the second layer are covered by the spheres of the third layer.
 - (iv) In this arrangement spheres of the fourth layer are exactly aligned with those of the first layer.
25. In which of the following structures coordination number for cations and anions in the packed structure will be same?
- (i) Cl^- ion form *fcc* lattice and Na^+ ions occupy all octahedral voids of the unit cell.
 - (ii) Ca^{2+} ions form *fcc* lattice and F^- ions occupy all the eight tetrahedral voids of the unit cell.
 - (iii) O^{2-} ions form *fcc* lattice and Na^+ ions occupy all the eight tetrahedral voids of the unit cell.
 - (iv) S^{2-} ions form *fcc* lattice and Zn^{2+} ions go into alternate tetrahedral voids of the unit cell.
26. What is the coordination number in a square close packed structure in two dimensions?
- (i) 2
 - (ii) 3
 - (iii) 4
 - (iv) 6
27. Which kind of defects are introduced by doping?
- (i) Dislocation defect
 - (ii) Schottky defect
 - (iii) Frenkel defects
 - (iv) Electronic defects
28. Silicon doped with electron-rich impurity forms _____.
- (i) *p*-type semiconductor
 - (ii) *n*-type semiconductor
 - (iii) intrinsic semiconductor
 - (iv) insulator
29. Which of the following statements is not true?
- (i) Paramagnetic substances are weakly attracted by magnetic field.
 - (ii) Ferromagnetic substances cannot be magnetised permanently.
 - (iii) The domains in antiferromagnetic substances are oppositely oriented with respect to each other.
 - (iv) Pairing of electrons cancels their magnetic moment in the diamagnetic substances.
30. Which of the following is not true about the ionic solids?
- (i) Bigger ions form the close packed structure.
 - (ii) Smaller ions occupy either the tetrahedral or the octahedral voids depending upon their size.
 - (iii) Occupation of all the voids is not necessary.

- (iv) The fraction of octahedral or tetrahedral voids occupied depends upon the radii of the ions occupying the voids
31. A ferromagnetic substance becomes a permanent magnet when it is placed in a magnetic field because _____.
- all the domains get oriented in the direction of magnetic field.
 - all the domains get oriented in the direction opposite to the direction of magnetic field.
 - domains get oriented randomly.
 - domains are not affected by magnetic field
32. The correct order of the packing efficiency in different types of unit cells is _____.
- $fcc < bcc < \text{simple cubic}$
 - $fcc > bcc > \text{simple cubic}$
 - $fcc < bcc > \text{simple cubic}$
 - $bcc < fcc > \text{simple cubic}$
33. Which of the following defects is also known as dislocation defect?
- Frenkel defect
 - Schottky defect
 - Non-stoichiometric defect
 - Simple interstitial defect
34. In the cubic close packing, the unit cell has _____.
- 4 tetrahedral voids each of which is shared by four adjacent unit cells.
 - 4 tetrahedral voids within the unit cell.
 - 8 tetrahedral voids each of the which is shared by four adjacent unit cells.
 - 8 tetrahedral voids within the unit cells
35. Which of the following represents correct order of conductivity in solids?
- $\kappa \text{ metals} \gg \kappa \text{ insulators} < \kappa \text{ semiconductors}$
 - $\kappa \text{ metals} \ll \kappa \text{ insulators} < \kappa \text{ semiconductors}$
 - $\kappa \text{ metals} \cong \kappa \text{ semiconductors} > \kappa \text{ insulators} = \text{zero}$
 - $\kappa \text{ metals} < \kappa \text{ semiconductors} > \kappa \text{ insulators} \neq \text{zero}$

Multiple Choice Questions

36. Which of the following is not true about the voids formed in 3 dimensional hexagonal close packed structure?
- A tetrahedral void is formed when a sphere of the second layer is present above triangular void in the first layer.
 - All the triangular voids are not covered by the spheres of the second layer.
 - Tetrahedral voids are formed when the triangular voids in the second layer lie above the triangular voids in the first layer and the triangular shapes of these voids do not overlap.
 - Octahedral voids are formed when the triangular voids in the second layer exactly overlap with similar voids in the first layer.
37. The value of magnetic moment is zero in the case of antiferromagnetic substances because the domains _____.
- get oriented in the direction of the applied magnetic field.
 - get oriented opposite to the direction of the applied magnetic field.

- (iii) are oppositely oriented with respect to each other without the application of magnetic field.
- (iv) cancel out each other's magnetic moment
38. Which of the following statements are not true?
- (i) Vacancy defect results in a decrease in the density of the substance.
 - (ii) Interstitial defects results in an increase in the density of the substance.
 - (iii) Impurity defect has no effect on the density of the substance.
 - (iv) Frankel defect results in an increase in the density of the substance
39. Which of the following statements are true about metals?
- (i) Valence band overlaps with conduction band.
 - (ii) The gap between valence band and conduction band is negligible.
 - (iii) The gap between valence band and conduction band cannot be determined.
 - (iv) Valence band may remain partially filled.
40. Under the influence of electric field, which of the following statements is true about the movement of electrons and holes in a p -type semi conductor?
- (i) Electron will move towards the positively charged plate through electron holes.
 - (ii) Holes will appear to be moving towards the negatively charged plate.
 - (iii) Both electrons and holes appear to move towards the positively charged plate.
 - (iv) Movement of electrons is not related to the movement of holes.
41. Which of the following statements are true about semiconductors?
- (i) Silicon doped with electron rich impurity is a p -type semiconductor.
 - (ii) Silicon doped with an electron rich impurity is an n -type semiconductor.
 - (iii) Delocalised electrons increase the conductivity of doped silicon.
 - (iv) An electron vacancy increases the conductivity of n -type semiconductor
42. An excess of potassium ions makes KCl crystals appear violet or lilac in colour since _____.
- (i) some of the anionic sites are occupied by an unpaired electron.
 - (ii) some of the anionic sites are occupied by a pair of electrons.
 - (iii) there are vacancies at some anionic sites.
 - (iv) F-centres are created which impart colour to the crystals.
45. The number of tetrahedral voids per unit cell in NaCl crystal is _____.
- (i) 4
 - (ii) 8
 - (iii) twice the number of octahedral voids.
 - (iv) four times the number of octahedral voids
46. Amorphous solid can also be called _____.
- (i) pseudo solids
 - (ii) true solids
 - (iii) super cooled liquids
 - (iv) super cooled solids
47. Which of the following statements are correct?
- (i) Ferrimagnetic substances lose ferrimagnetism on heating and become paramagnetic.

- (ii) Ferrimagnetic substances do not lose ferrimagnetism on heating and remain ferrimagnetic.
 - (iii) Antiferromagnetic substances have domain structures similar to ferromagnetic substances and their magnetic moments are not cancelled by each other.
 - (iv) In ferromagnetic substances all the domains get oriented in the direction of magnetic field and remain as such even after removing magnetic field.
48. Which of the following features are not shown by quartz glass?
- (i) This is a crystalline solid.
 - (ii) Refractive index is same in all the directions.
 - (iii) This has definite heat of fusion.
 - (iv) This is also called super cooled liquid.
49. Which of the following cannot be regarded as molecular solid?
- (i) SiC (Silicon carbide)
 - (ii) AlN
 - (iii) Diamond
 - (iv) I₂
50. In which of the following arrangements octahedral voids are formed?
- (i) *hcp*
 - (ii) *bcc*
 - (iii) simple cubic
 - (iv) *fcc*
51. Frenkel defect is also known as _____.
- (i) stoichiometric defect
 - (ii) dislocation defect
 - (iii) impurity defect
 - (iv) non-stoichiometric defect
52. Which of the following defects decrease the density?
- (i) Interstitial defect
 - (ii) Vacancy defect
 - (iii) Frankel defect
 - (iv) Schottky defect

Short Answer Type

53. Why are liquids and gases categorised as fluids?
54. Why are solids incompressible?
55. In spite of long range order in the arrangement of particles why are the crystals usually not perfect?
56. Why does table salt, NaCl, some times appear yellow in colour?
57. Why is FeO (s) not formed in stoichiometric composition?
58. Why does white ZnO (s) becomes yellow upon heating?
59. Why does the electrical conductivity of semiconductors increase with rise in temperature?
60. Explain why does conductivity of germanium crystals increase on doping with gallium.
61. In a compound, nitrogen atoms (N) make cubic close packed lattice and metal atoms (M) occupy one-third of the tetrahedral voids present. Determine the

formula of the compound formed by M and N?

62. Under which situations can an amorphous substance change to crystalline form?

63. What is the structure of the crystal with co-ordination number 8?

64. What is the co-ordinations number of each ion, if the radius ratio of the crystal is 0.83?

65. Solid is a very hard electrical insulator in solid as well as in molten state and melts at extremely high temperature. What type of solid is it?

66. Give any two difference between schottky and frenkel defects in ionic solids

In the following questions match the items given in Column I with the items given in Column II. In some questions more than one item of Column I and Column II may match.

67. Match the defects given in Column I with the statements in given Column II.

Column I	Column II
(i) Simple vacancy defect	(a) shown by non-ionic solids and increases density of the solid.
(ii) Simple interstitial defect	(b) shown by ionic solids and decreases density of the solid.
(iii) Frenkel defect	(c) shown by non ionic solids and density of the solid decreases
(iv) Schottky defect	(d) shown by ionic solids and density of the solid remains the same.

68. Match the type of unit cell given in Column I with the features given in Column II.

Column I	Column II
(i) Primitive cubic unit cell	(a) Each of the three perpendicular edges compulsorily have the different edge length i.e; $a \neq b \neq c$.
(ii) Body centred cubic unit cell	(b) Number of atoms per unit cell is one.
(iii) Face centred cubic unit cell	(c) Each of the three perpendicular edges compulsorily have the same edge length i.e; $a = b = c$
(iv) End centred orthorhombic unit cell	(d) In addition to the contribution from the corner atoms the number of atoms present in a unit cell is one
	(e) In addition to the contribution from the corner atoms the number of atoms present in a unit cell is three.

69. Match the types of defect given in Column I with the statement given in Column II.

Column I	Column II
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- (i) Impurity defect (a) NaCl with anionic sites called F-centres
(ii) Metal excess defect (b) FeO with Fe³⁺
(iii) Metal deficiency defect (c) NaCl with Sr²⁺ and some cationic sites vacant

70. Match the items given in Column I with the items given in Column II.

- | Column I | Column II |
|----------------------------------------|----------------------------------|
| (i) Mg in solid state | (a) <i>p</i> -Type semiconductor |
| (ii) MgCl ₂ in molten state | (b) <i>n</i> -Type semiconductor |
| (iii) Silicon with phosphorus | (c) Electrolytic conductors |
| (iv) Germanium with boron | (d) Electronic conductors |

71. Match the type of packing given in Column I with the items given in Column II.

- | Column I | Column II |
|---------------------------------------------------|----------------------------------------------------------|
| (i) Square close packing in two dimensions | (a) Triangular voids |
| (ii) Hexagonal close packing in two dimensions | (b) Pattern of spheres is repeated in every fourth layer |
| (iii) Hexagonal close packing in three dimensions | (c) Coordination number 4 |
| (iv) Cubic close packing in three dimensions | (d) Pattern of sphere is repeated in alternate layers |

Long Answer Type

72. Show that in a cubic close packed structure, eight tetrahedral voids are present per unit cell.
73. How does the doping increase the conductivity of semiconductors?
74. A sample of ferrous oxide has actual formula Fe_{0.93} O_{1.00}. In this sample what fraction of metal ions are Fe²⁺ ions? What type of nonstoichiometric defect is present in this sample?
75. Calculate the packing efficiency in a simple cubic lattice.
76. An element X has a density of 6.23 g/cm³. If the edge length of the unit cell is 400 pm, identify the type of cubic unit cell. (Molar mass of X = 60g/mol, N_A = 6.022 × 10²³ mol⁻¹)
77. What is packing efficiency in a crystal? Draw the unit cell of a simple cubic lattice and calculate the packing efficiency in a simple cubic lattice
78. Calculate the packing efficiency in a body centred cubic lattice .